Halide Perovskite Semiconductors and Solar Cells

Hybrid organic inorganic semiconductors (HOIS) witnessed a renaissance from the due to the performanc of the halide perovskite HOIS in photovoltaic applications Since the identification of HOIS for PV applications ju under a decade ago the efficies have surpassed all other poly crystallie thin film technologies with record cell efficiencies in excess of 5%2. This talkwill provide an overview of NREL efforts, progress and challenges in hali perovskite solar cells with an emphasis on the role of th interface in device performance indlug stability. The importance of Pb as an enabling element in these materia and question regarding impact for the use of Pb base HOIS for terawatt scale PV will be discussed an examination of different perovskite active layers and interfacial electonic structure of these remarkable materials will be presented and connected to basic question regarding stability he extent to which other low dimensional HOIS system provide a unique avenue modulate the interfaces and enable performance/stability will also be discuss. The discussion will then pivot to the larger opportunity for material functionality which lower dimensionality provides for applications beyond traditiona PV. Specifically, the work within the NREL lead Center Hybrid Organic Inganic Semiconductors for Energy (CHOISE), US Department of Energy, Energy Front Research Center (EFRC) to exploit the hybrid aspects these materials for spintronic functionality will be discussed. Characterizatifnom a range of time resolved spectoscopy, structuralchemicaland device level studies will be presented.

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> Theoretical and Applied Physics

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Wednesday,February 12th 4:00 PM Innovation Hall Room E430

Refreshments will be available at 3:30 PM. In E217

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Bio:

Dr. Berry is currently the team lead for the Nati